# TOSHIBA

Unit: mm

**TLP281** 

 $7.0 \pm 0.4$ 

Half Pitch Mini Flat 4 nin

 $0.6 \pm 0.3$ 

TOSHIBA PHOTOCOUPLER IRED & PHOTO-TRANSISTOR

# TLP281, TLP281-4

### PROGRAMMABLE CONTROLLERS AC/DC-INPUT MODULE PC CARD MODEM(PCMCIA)

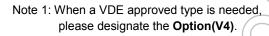
TLP281 and TLP281-4 is a very small and thin coupler, suitable for surface mount assembly in applications such as PCMCIA Fax modem, programmable controllers. TLP281 and TLP281-4 consist of photo transistor, optically coupled

to an infrared emitting diode.

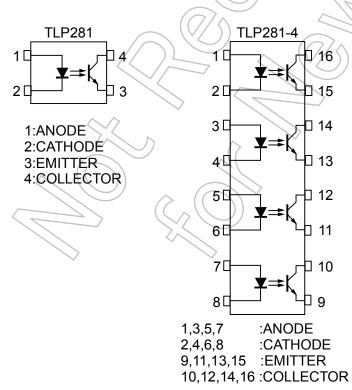
- Collector-Emitter Voltage : 80 V (min)
- Current Transfer Ratio : 50% (min) Rank GB : 100% (min)
  - : 100% (min) : 2500 Vrms (min)
- Isolation VoltageUL-recognized
- : UL 1577, File No.E67349

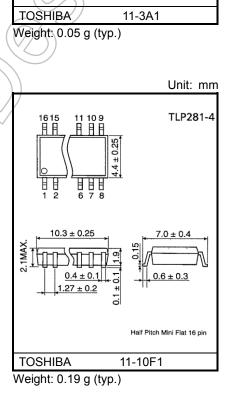
File No.E67349

- cUL-recognized
- : CSA Component Acceptance Service No.5A
- VDE-approved
- : EN 60747-5-5 (Note 1)



## Pin Configuration (top view)





 $2.6 \pm 0.25$ 

0.4 ± 0.

1.27 ± 0.2

Start of commercial production 1996-03

# TOSHIBA

### **Current Transfer Ratio**

| TYPE      | Classification<br>(Note 1) | Current Transfer Ration (%)<br>(I <sub>C</sub> /I <sub>F</sub> )           I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V, Ta = 25°C           Min         Max |     | Marking of Classification                                     |
|-----------|----------------------------|--|-----|---|
|           | Blank                      | 50   | 600 | Blank, Y <sup>∎</sup> , YE, G, G <sup>∎</sup> , GR, B, BL, GB |
|           | Rank Y                     | 50   | 150 | YE, Y   |
|           | Rank GR                    | 100  | 300 | GR, G, G <sup>∎</sup>   |
|           | Rank BL                    | 200  | 600 | BL, B   |
| TLP281    | Rank GB                    | 100  | 600 | GB, GR, G, G <sup>,</sup> , BL, B                             |
|           | Rank YH                    | 75   | 150 | Y"  |
|           | Rank GRL                   | 100  | 200 | G   |
|           | Rank GRH                   | 150  | 300 | G   |
|           | Rank BLL                   | 200  | 400 | B   |
| TLP281-4  | Blank                      | 50   | 600 | Blank, GB   |
| 1LF 201-4 | Rank GB                    | 100  | 600 | GB  |

Note 1: Ex. rank GB: TLP281 (GB)

Note: Application type name for certification test, please use standard product type name, i.e. TLP281 (GB): TLP281, TLP281-4 (GB): TLP281-4

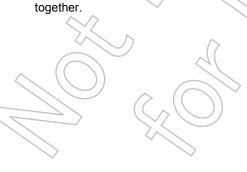
#### Absolute Maximum Ratings (Ta = 25°C)

|                |  |                     |                 |                |       | -                      |
|----------------|--|---------------------|-----------------|----------------|-------|------------------------|
| CHARACTERISTIC |  | EVMDO               | RATING          |                |       |                        |
|                | CHARACTERISTIC   | SYMBOL              | TLP281          | TLP281-4       | UNIT  |                        |
|                | Forward Current  | lF                  | 5               | 0              | mA    |                        |
|                | Forward Current Derating                                     | ∆IF/°C              | -0.7 (Ta≥53°C)  | -0.5 (Ta≥25°C) | mA/°C |                        |
| ED             | Pulse Forward Current<br>(100 μs pulse, 100 pps)             | IFP                 |                 | 1              | A     |                        |
| Ш              | Reverse Voltage  | VR                  | Ę               | 5              | (v)   | $\mathbf{r}$           |
|                | Diode power dissipation                                      | PD                  | 100             | 70             | mW    | 2                      |
|                | Diode power dissipation derating                             | ∆P <sub>D</sub> /°C | -1.39 (Ta≥53°C) | -0.7 (Ta≥25°C) | mW/°C |                        |
|                | Junction Temperature   | Tj                  | 12              | 25             | )°C   |                        |
|                | Collector-Emitter Voltage                                    | V <sub>CEO</sub>    | 8               | 0 (())         | V V   |                        |
|                | Emitter-Collector Voltage                                    | VECO                | 7               |                | V     | $\frown$               |
| OR             | Collector Current  | lc                  | 5               | o 2( >>        | mA    | $\langle \cap \rangle$ |
| DETECTOR       | Collector Power Dissipation (1 Circuit)                      | Pc                  | 150             | 100            | mW    |                        |
|                | Collector Power Dissipation<br>Derating(Ta≥25°C) (1 Circuit) | ∆Pc/°C              | -1.5            | -1.0           | mW/°C | 20)                    |
|                | Junction Temperature   | Tj                  | 12              | 25             | °C    |                        |
| Ope            | erating Temperature Range                                    | T <sub>opr</sub>    | -55 to 100      |                | (C)   |                        |
| Stor           | rage Temperature Range                                       | T <sub>stg</sub>    | -55 to          | o 125          | °¢    |                        |
| Lea            | d Soldering Temperature (10 s)                               | T <sub>sol</sub>    | 26              | 50             | ))°C  |                        |
| (1 C           | al Package Power Dissipation<br>Circuit)                     | Рт                  | 200             | 170            | mW    |                        |
|                | al Package Power Dissipation<br>ating (Ta≥25°C) (1 Circuit)  | ∆Pt/°C              | -2.0            | -1.7           | mW/°C |                        |
|                | ation Voltage<br>, 60 s, R.H.≤ 60 %)     (Note 1)            | BVs                 | 25              | 00             | Vrms  |                        |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device : LED side pins shorted together and DETECTOR side pins shorted



**Electrical Characteristics (Ta = 25°C)** 

| CHARACTERISTIC |                                     | SYMBOL          | TEST CONDITION                           | MIN | TYP. | MAX | UNIT |  |
|----------------|-------------------------------------|-----------------|--|-----|------|-----|------|--|
|                | Forward Voltage                     | VF              | IF = 10 mA                               | 1.0 | 1.15 | 1.3 | V    |  |
| LED            | Reverse Current                     | IR              | V <sub>R</sub> = 5 V                     | _   | _    | 10  | μA   |  |
|                | Capacitance                         | Ст              | V = 0 V, f = 1 MHz                       | 1   | 30   | _   | pF   |  |
|                | Collector-Emitter Breakdown Voltage | V(BR) CEO       | IC = 0.5 mA                              | 80  | -    | _   | V    |  |
|                | Emitter-Collector Breakdown Voltage | V(BR) ECO       | I <sub>E</sub> = 0.1 mA                  | (7) | 2    |     | V    |  |
| DETECTOR       | Collector Dark Current<br>(Note 1)  | ICEO            | V <sub>CE</sub> = 48 V                   |     | 0.01 | 0.1 |      |  |
|                |                                     |                 | Ambient Light Below (100 lx)<br>(Note 2) | ))  | 2    | 10  | μA   |  |
|                |                                     |                 | V <sub>CE</sub> = 48 V, Ta = 85 °C       |     | 2    | 50  |      |  |
|                |                                     |                 | Ambient Light Below (100 &x)<br>(Note 2) | _   | 4    | 50  | μA   |  |
|                | Capacitance (Collector to Emitter)  | C <sub>CE</sub> | V = 0 V, f = 1 MHz                       | _   | 10   | -   | pF   |  |

Note 1: Because of the construction,leak current might be increased by ambient light. Please use photocoupler with less ambient light.

Note 2: Irradiation to marking side using standard light bulb.

## Coupled Electrical Characteristics (Ta = 25°C)

| CHARACTERISTIC                          | SYMBOL              |  | MIN | TYP. | MAX | UNIT |
|---|---------------------|--|-----|------|-----|------|
| Current Transfer Ratio                  | IC/IF               | IF = 5 mA, VCE = 5 ∀                           | 50  |      | 600 | %    |
|   | Rank GB             |  | 100 | —    | 600 | 70   |
| Saturated CTR                           | IC/IF(sat)          | I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.4 V | —   | 60   | _   | %    |
|   |                     | Rank GB  | 30  | _    | —   | 70   |
|   | ( )                 | IC = 2.4 mA, IF = 8 mA                         | _   | _    | 0.4 |      |
| Collector-Emitter<br>Saturation Voltage | VCE(sat)            | lc = 0.2 mA, l⊧ = 1 mA                         | _   | 0.2  | —   | V    |
|   |                     | Rank GB  | _   | _    | 0.4 |      |
| Off-State Collector Current             | I <sub>C(off)</sub> | VF = 0.7 V, V <sub>CE</sub> = 48 V             |     |      | 10  | μA   |

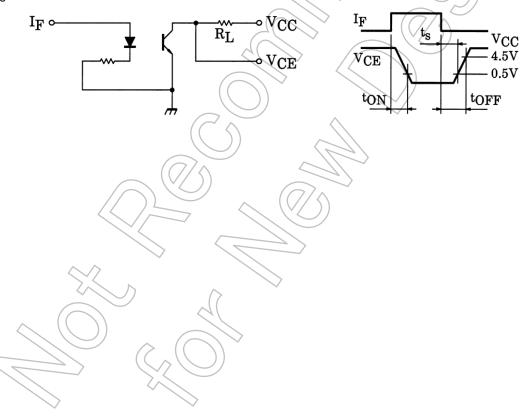
## Isolation Characteristics (Ta = 25°C)

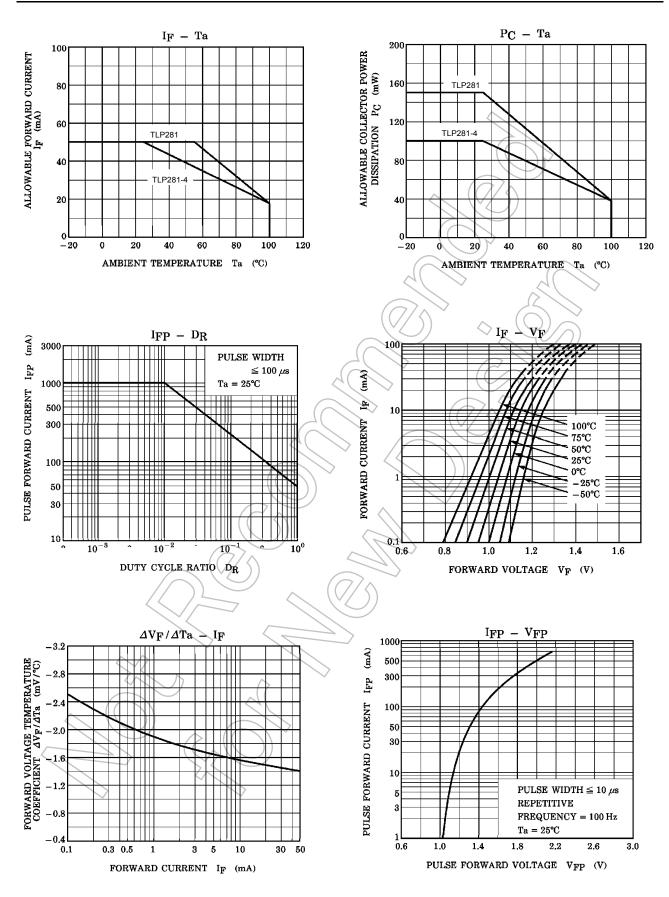
| CHARACTERISTIC                   | SYMBOL | TEST CONDITION                      | MIN                | TYP.             | MAX | UNIT |
|----------------------------------|--------|-------------------------------------|--------------------|------------------|-----|------|
| Capacitance<br>(Input to Output) | Cs     | V <sub>S</sub> = 0 V, f = 1 MHz     | _                  | 0.8              |     | pF   |
| Isolation Resistance             | Rs     | V <sub>S</sub> = 500 V, R.H. ≤ 60 % | 5×10 <sup>10</sup> | 10 <sup>14</sup> | -   | Ω    |
| Isolation Voltage                | BVS    | AC, 60 s                            | 2500               |                  |     | Vrms |

## Switching Characteristics (Ta = 25°C)

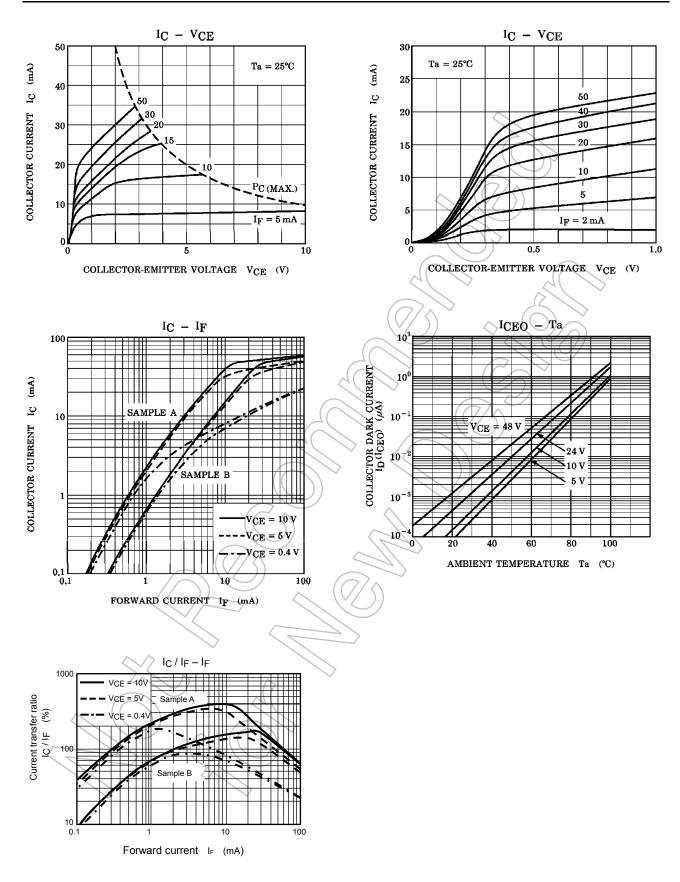
| CHARACTERISTIC | SYMBOL | TEST CONDITION MIN TYP. MAX UNIT   |
|----------------|--------|--|
| Rise Time      | tr     | _ 2 _  |
| Fall Time      | tf     | V <sub>CC</sub> = 10 V, I <sub>C</sub> = 2,mA - 3 -  |
| Turn-On Time   | ton    | $R_L = 100 \Omega$ $\mu s$   |
| Turn-Off Time  | toff   |  |
| Turn-On Time   | ton    |  |
| Storage Time   | ts     | $\begin{array}{c c} R_L = 1.9 \text{ k}\Omega & (Fig.1) \\ V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA} & -25  \mu\text{s} \end{array}$ |
| Turn-Off Time  | tOFF   | 40 -   |

Fig.1: SWITCHING TIME TEST CIRCUIT

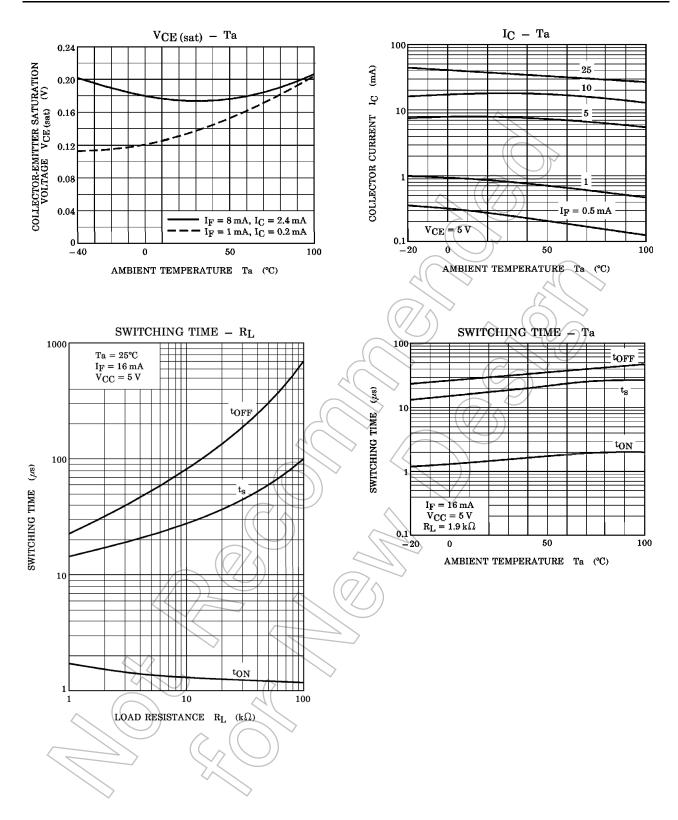




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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